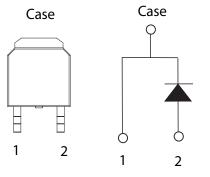
Littelfuse Power

GEN2 SiC Schottky Diode LSIC2SD065C20A, 650 V, 20 A, TO-252-2L (DPAK)

LSIC2SD065C20A 650 V, 20 A SiC Schottky Barrier Diode



Circuit Diagram TO-252-2L (DPAK)



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability

HF

RoHS

Po

- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

• Solar inverters

EV charging stations

Applications

- Boost diodes in PFC or DC/DC stages
 - Industrial motor drives
- Switch-mode power supplies
- Uninterruptible power supplies

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
Continuous Forward Current		T _c = 25 °C	45	^	
	I F	T _c = 135 °C	20	A	
Non-Repetitive Forward Surge Current	I _{FSM}	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	90	A	
Power Dissipation	D	$T_c = 25 \text{ °C}$	135	W	
	P _{Tot}	$T_c = 110 \text{ °C}$	60		
Operating Junction Temperature	TJ	-	-55 to 175	°C	
Storage Temperature	T _{stg}	-	-55 to 150	°C	
Soldering Temperature (reflow MSL1)	T _{sold}	-	260	°C	

Electrical Characteristics							
Characteristics S		Conditions	Value				
	Symbol		Min.	Тур.	Max.	Unit	
Forward Voltage		I _F = 20 A, T _J = 25 °C	-	1.5	1.8	V	
	V _F	I _F = 20 A, T _J = 175 °C	-	1.85	-	V	
Reverse Current		$V_{_{ m R}} = 650 \text{ V}$, $T_{_{ m J}} = 25 ^{\circ}\text{C}$	-	<1	50	μA	
	R	$V_{_{ m R}} = 650 \text{ V}$, $T_{_{ m J}} = 175 \text{ °C}$	-	60	-	μΑ	
Total Capacitance		$V_{R} = 1 V$, f = 1 MHz	-	960	-		
	С	$V_{_{\rm R}} = 200 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	120	-	pF	
		$V_{_{\rm R}} = 400 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	86	-		
Total Capacitive Charge	Q _c	$V_{R} = 400 \text{ V}, \ \text{Q}_{c} = \int_{0}^{V_{R}} C(V) dV$	-	63	-	nC	

Thermal Characteristics						
Characteristics	Symbol	Value	Unit			
Thermal Resistance	R _{eJC}	1.1	°C/W			

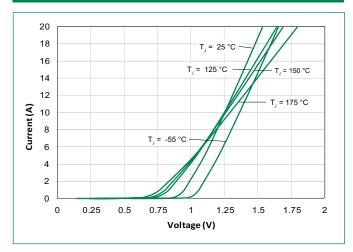


Figure 1: Typical Foward Characteristics

Figure 2: Typical Reverse Characteristics

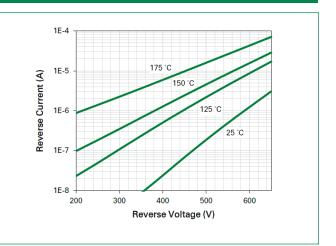


Figure 3: Power Derating

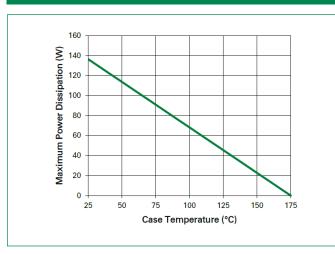
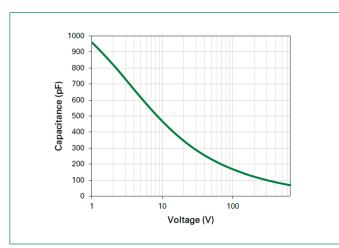
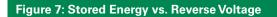


Figure 5: Capacitance vs. Reverse Voltage





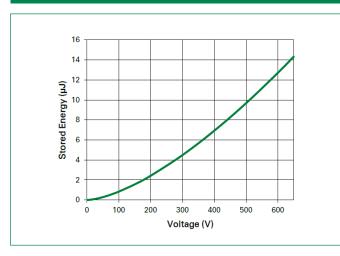


Figure 4: Current Derating

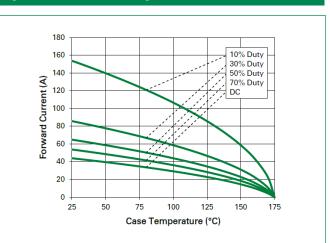


Figure 6: Capacitive Charge vs. Reverse Voltage

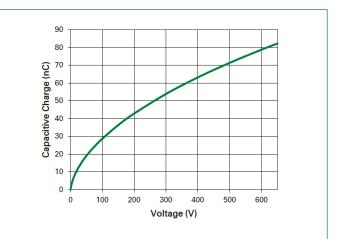
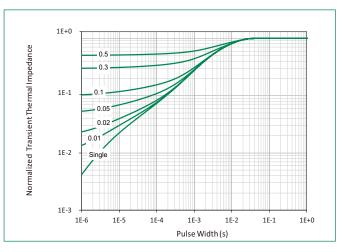
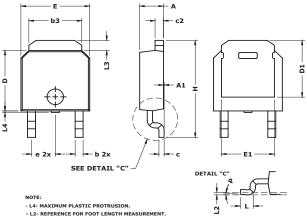


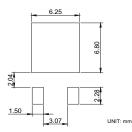
Figure 8: Transient Thermal Impedance



Dimensions TO-252-2L (DPAK)

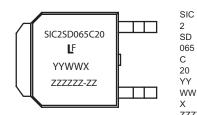


Recommended Solder Pattern Layout



Symbol		Inches		N	Aillimeters		
Зупрог	Min	Nom	Max	Min	Nom	Max	
А	0.085	0.090	0.095	2.16	2.29	2.41	
A1	0	0.003	0.005	0	0.08	0.13	
b	0.025	0.030	0.035	0.64	0.76	0.89	
b3	0.195	0.200	0.215	4.95	5.08	5.46	
С	0.018	0.020	0.024	0.46	0.51	0.61	
C2	0.018	0.032	0.035	0.46	0.81	0.89	
D	0.235	0.240	0.245	5.97	6.10	6.22	
D1	0.205	-	-	5.21	-	-	
E	0.250	0.260	0.265	6.35	6.60	6.73	
E1	0.170	-	-	4.32	-	-	
е	0	.090 BSC		2.29 BSC			
Н	0.370	0.387	0.410	9.40	9.83	10.41	
L	0.040	0.045	0.050	1.02	1.14	1.27	
L2	0.010 BSC			0.25 BSC			
L3	0.035	-	0.050	0.89	-	1.27	
L4	0	-	0.006	0	-	0.15	
Р	0°	-	8 °	0°	-	8 °	

Part Numbering and Marking System



2	= SiC Diode
	= Gen2
)	= Schottky Diode
5	= Voltage Rating (650 V)
	= TO-252-2L (DPAK)
	= Current Rating (20 A)
,	= Year

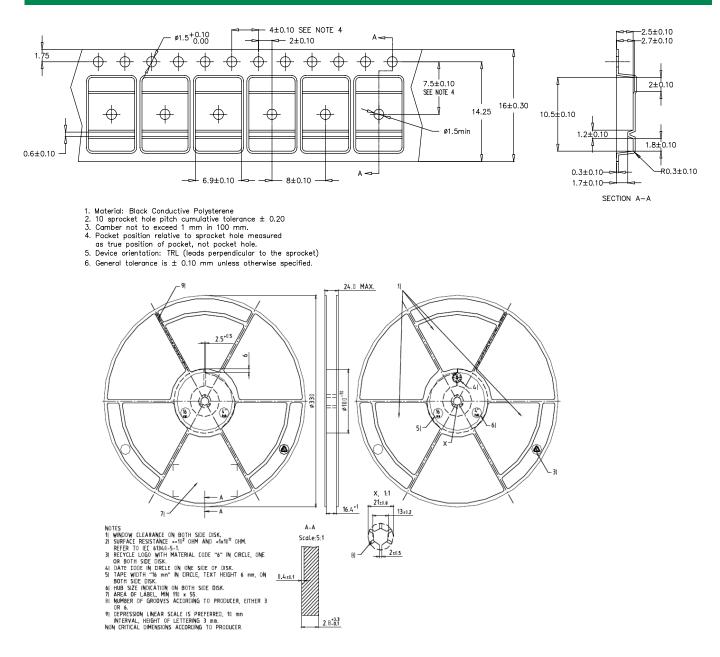
- = Week
- = Special code

X = Special code ZZZZZZ-ZZ = Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065C20A	SIC2SD065C20	Tape and Reel	2500

Carrier Tape & Reel Specification TO-252-2L (DPAK)



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